

LM2990 **Negative Low Dropout Regulator**

General Description

The LM2990 is a three-terminal, low dropout, 1 ampere negative voltage regulator available with fixed output voltages of -5, -5.2, -12, and -15V.

The LM2990 uses new circuit design techniques to provide low dropout and low quiescent current. The dropout voltage at 1A load current is typically 0.6V and a guaranteed worstcase maximum of 1V over the entire operating temperature range. The quiescent current is typically 1 mA with 1A load current and an input-output voltage differential greater than 3V. A unique circuit design of the internal bias supply limits the quiescent current to only 9 mA (typical) when the regulator is in the dropout mode ($V_{OUT} - V_{IN} \le 3V$). Output voltage accuracy is guaranteed to ±5% over load, and temperature extremes.

The LM2990 is short-circuit proof, and thermal shutdown includes hysteresis to enhance the reliability of the device when overloaded for an extended period of time. The

LM2990 is available in a 3-lead TO-220 package and is rated for operation over the automotive temperature range of -40°C to +125°C.

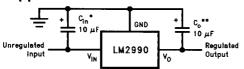
Features

- 5% output accuracy over entire operating range
- Output current in excess of 1A
- Dropout voltage typically 0.6V at 1A load
- Low quiescent current
- Internal short circuit current limit
- Internal thermal shutdown with hysteresis
- Functional complement to the LM2940 series

Applications

- Post switcher regulator
- Local, on-card, regulation
- Battery operated equipment

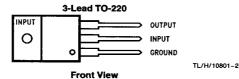
Typical Application



TL/H/10801-1

- *Required if the regulator is located further than 6 inches from the power supply filter capacitors. A 1 μF solid tantalum or a 10 μF aluminum electrolytic capacitor is recommended.
- **Required for stability. Must be at least a 10 µF aluminum electrolytic or a 1 µF solid tantalum to maintain stability. May be increased without bound to maintain regulation during transients. Locate the capacitor as close as possible to the regulator. The equivalent series resistance (ESR) is critical, and should be less than 10Ω over the same operating temperature range as the regulator.

Connection Diagram and Ordering Information



Order Number LM2990T-5.0, LM2990T-5.2, LM2990T-12 or LM2990T-15 See NS Package Number T03B

TO-263 Surface-Mount Package OUTPUT TAB IS GND

INPUT TL/H/10801-11 **Top View**

□ GND



Side View

Order Number LM2990S-5.0. LM2990S-12 or LM2990S-15 See NS Package Number TS3B

Temperature		Daalsana				
Range	-5.0	-5.2	-12	-15	Package	
-40°C to +125°C	LM2990T-5.0	LM2990T-5.2	LM2990T-12	LM2990T-15	TO-220	
	LM2990S-5.0		LM2990S-12	LM2990S-15	TO-263	

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Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

-26V to +0.3VInput Voltage

ESD Susceptibility (Note 2) 2 kV Power Dissipation (Note 3) Internally Limited

125°C Junction Temperature (T_{Jmax})

-65°C to +150°C Storage Temperature Lead Temperature (Soldering, 10 sec.) 260°C

Operating Ratings (Note 1)

-40°C to +125°C Junction Temperature Range (T_J) Maximum Input Voltage (Operational) -26V

Electrical Characteristics $V_{IN} = -5V + V_{O(NOM)}$ (Note 6), $I_O = 1A$, $C_O = 47 \mu F$, unless otherwise specified. Boldface limits apply over the entire operating temperature range, −40°C ≤ T_J ≤ 125°C, all other limits apply for T_J = 25°C.

Parameter		LM2990-5.0		LM2990-5.2		
	Conditions	Typ (Note 4)	Limit (Note 5)	Typ (Note 4)	Limit (Note 5)	Units (Limit)
Output Voltage (Vo)	5 mA ≤ I _O ≤ 1A	5	-4.90 -5.10	5.2	-5.10 -5.30	V (max) V (min) V
	5 mA ≤ I _O ≤ 1A		-4.75 -5.25		-4.94 -5.46	V V (max) V (min)
Line Regulation	$I_{O} = 5 \text{ mA},$ $V_{O(NOM)} - 1V > V_{IN} > -26V$	4	40	4	40	mV (max)
Load Regulation	50 mA ≤ I _O ≤ 1A	1	40	1	40	mV (max)
Dropout Voltage	$I_{O} = 0.1A, \Delta V_{O} \le 100 \text{ mV}$	0.1	0.3	0.1	0.3	V (max)
	$I_{O} = 1A$, $\Delta V_{O} \leq 100 \text{ mV}$	0.6	1	0.6	1	V (max)
Quiescent Current (Iq)	I _O ≤ 1A	1	5	1	5	mA (max)
	$I_O = 1A$, $V_{IN} = V_{O(NOM)}$	9	50	9	50	mA (max)
Short Circuit Current	$R_L = 1\Omega$ (Note 7)	1.8	1.5	1.8	1.5	A (min)
Maximum Output Current	(Note 7)	1.8	1.5	1.8	1.5	A (min)
Ripple Rejection	V _{ripple} = 1 V _{rms} , f _{ripple} = 1 kHz, l _O = 5 mA	58	50	58	50	dB (min)
Output Noise Voltage	10 Hz-100 kHz, I _O = 5 mA	250	750	250	750	μV (max)
Long Term Stability	1000 Hours	2000		2000		ppm

Electrical Characteristics $V_{IN} = -5V + V_{O(NOM)}$ (Note 6), $I_O = 1A$, $C_O = 47 \,\mu\text{F}$, unless otherwise specified. **Boldface** limits apply over the entire operating temperature range, $-40^{\circ}\text{C} \le T_J \le 125^{\circ}\text{C}$, all other limits apply for $T_J = 25^{\circ}\text{C}$. (Continued)

Parameter		LM2990-12		LM2990-15		
	Conditions	Typ (Note 4)	Limit (Note 5)	Typ (Note 4)	Limit (Note 5)	Units (Limit)
Output Voltage (V _O)	5 mA ≤ I _O ≤ 1A	– 12	-11.76 -12.24	-15	-14.70 -15.30	V (max) V (min)
	5 mA ≤ I _O ≤ 1A	- 12	- 11.40 - 12.60		- 14.25 - 15.75	V (max) V (min)
Line Regulation	$I_{O} = 5 \text{ mA},$ $V_{O(NOM)} - 1V > V_{IN} > -26V$	6	60	6	60	mV (max)
Load Regulation	50 mA ≤ i _O ≤ 1A	3	50	3	50	mV (max)
Dropout Voltage	$I_{O}=0.1A$, $\Delta V_{O}\leq 100$ mV	0.1	0.3	0.1	0.3	V (max)
	$I_{O} = 1A$, $\Delta V_{O} \leq 100 \text{ mV}$	0.6	1	0.6	1	V (max)
Quiescent Current (Iq)	l _O ≤ 1A	1	5	1	5	mA (max)
	$I_O = 1A, V_{IN} = V_{O(NOM)}$	9	50	9	50	mA (max)
Short Circuit Current	$R_L = 1\Omega$ (Note 7)	1.2	0.9	1.0	0.75	A (min)
Maximum Output Current	(Note 7)	1.8	1.4	1.8	1.4	A (min)
Ripple Rejection	V _{ripple} = 1 V _{rms} , f _{ripple} = 1 kHz, I _O = 5 mA	52	42	52	42	dB (min)
Output Noise Voltage	10 Hz-100 kHz, I _O = 5 mA	500	1500	600	1800	μV (max)
Long Term Stability	1000 Hours	2000		2000		ppm

Note 1: Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional, but do not guarantee specific performance limits. For guaranteed specifications and test conditions, see the Electrical Characteristics.

Note 2: Human body model, 100 pF discharged through a 1.5 kΩ resistor.

Note 3: The maximum power dissipation is a function of T_{Jmax} , θ_{JA} , and T_A . The maximum allowable power dissipation at any ambient temperature is $P_D = (T_{Jmax} - T_A)/\theta_{JA}$. If this dissipation is exceeded, the due temperature will nse above 125°C, and the LM2990 will eventually go into thermal shutdown at a T_J of approximately 160°C. For the LM2990, the junction-to-ambient thermal resistance, is 53°C/W, 73°C/W for the TO-263, and the junction-to-case thermal resistance is 3°C. If the TO-263 package is used, the thermal resistance can be reduced by increasing the P.C. board copper area thermally connected to the package. Using 0.5 square inches of copper area, θ_{JA} is 50°C/W; with 1 square inch of copper area, θ_{JA} is 37°C/W; and with 1.6 or more square inches of copper area, θ_{JA} is 32°C/W.

Note 4: Typicals are at T_J = 25°C and represent the most likely parametric norm.

Note 5: Limits are guaranteed and 100% production tested.

Note 6: VO(NOM) is the nominal (typical) regulator output voltage, -5V, -5.2V, -12V or -15V.

Note 7: The short circuit current is less than the maximum output current with the -12V and -15V versions due to internal foldback current limiting. The -5V and -5.2V versions, tested with a lower input voltage, does not reach the foldback current limit and therefore conducts a higher short circuit current level. If the LM2990 output is pulled above ground, the maximum allowed current sunk back into the LM2990 is 1.5A.

Definition of Terms

Dropout Voltage: The input-output voltage differential at which the circuit ceases to regulate against further reduction in input voltage. Measured when the output voltage has dropped 100 mV from the nominal value obtained at (V $_{\rm O}$ + 5V) input, dropout voltage is dependent upon load current and junction temperature.

Input Voltage: The DC voltage applied to the input terminals with respect to ground.

Input-Output Differential: The voltage difference between the unregulated input voltage and the regulated output voltage for which the regulator will operate.

Line Regulation: The change in output voltage for a change in the input voltage. The measurement is made under conditions of low dissipation or by using pulse techniques such that the average chip temperature is not significantly affected.

Load Regulation: The change in output voltage for a change in load current at constant chip temperature.

Long Term Stability: Output voltage stability under accelerated life-test conditions after 1000 hours with maximum rated voltage and junction temperature.

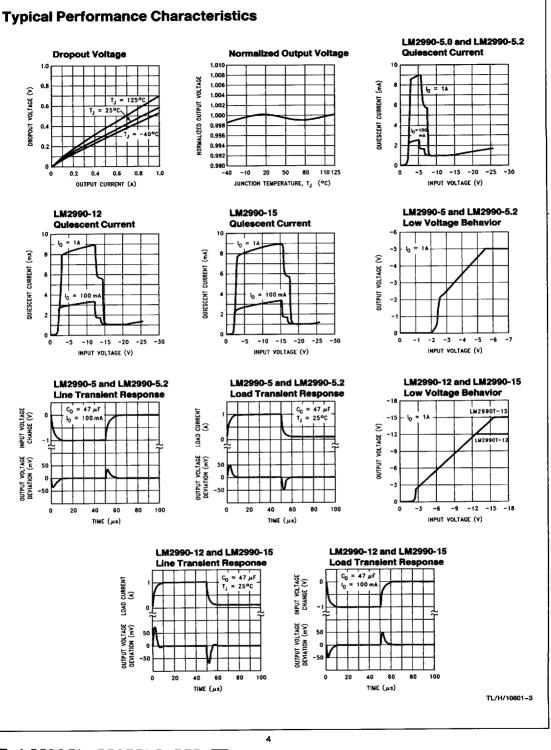
Output Noise Voltage: The rms AC voltage at the output, with constant load and no input ripple, measured over a specified frequency range.

Quiescent Current: That part of the positive input current that does not contribute to the positive load current. The regulator ground lead current.

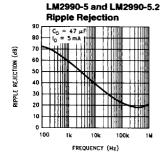
Ripple Rejection: The ratio of the peak-to-peak input ripple voltage to the peak-to-peak output ripple voltage.

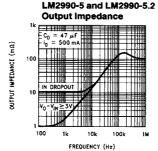
Temperature Stability of Vo: The percentage change in output voltage for a thermal variation from room temperature to either temperature extreme.

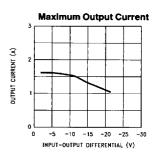
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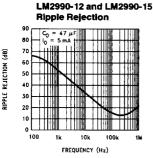


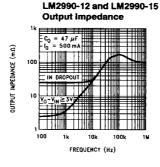
Typical Performance Characteristics (Continued)

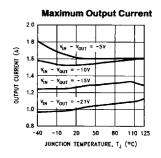


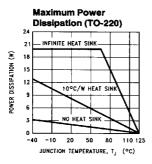


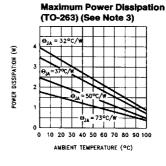








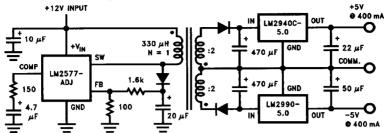




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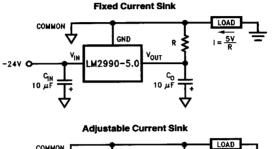
Typical Applications

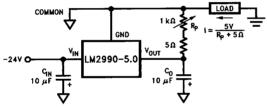
Post Regulator for an Isolated Switching Power Supply



TL/H/10801-5

The LM2490 is a positive 1A low dropout regulator; refer to its datasheet for further information.





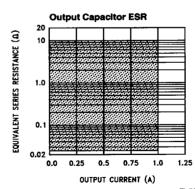
Application Hints

EXTERNAL CAPACITORS

The LM2990 regulator requires an output capacitor to maintain stability. The capacitor must be at least 10 μF aluminum electrolytic or 1 μF solid tantalum. The output capacitor's ESR must be less than 10 Ω , or the zero added to the regulator frequency response by the ESR could reduce the phase margin, creating oscillations (refer to the graph on the right). An input capacitor, of at least 1 μF solid tantalum or 10 μF aluminum electrolytic, is also needed if the regulator is situated more than 6" from the input power supply filter.

FORCING THE OUTPUT POSITIVE

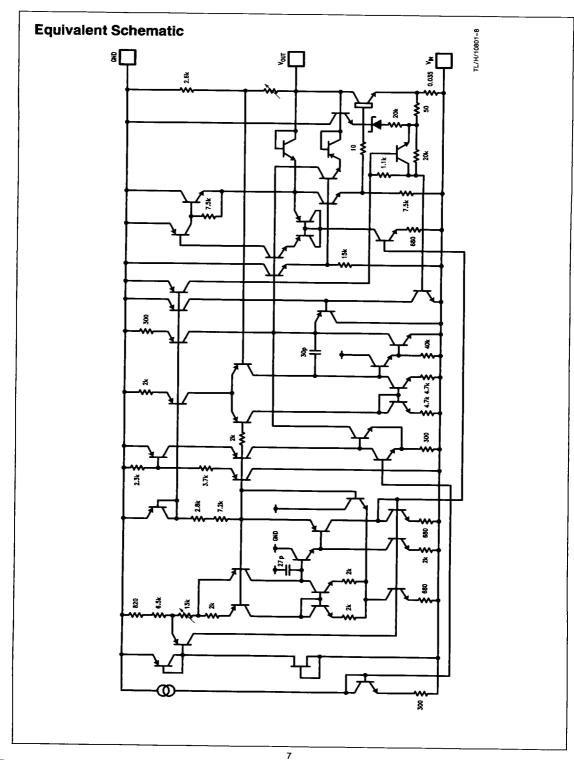
Due to an internal clamp circuit, the LM2990 can withstand positive voltages on its output. If the voltage source pulling the output positive is DC, the current must be limited to 1.5A. A current over 1.5A fed back into the LM2990 could damage the device. The LM2990 output can also withstand fast positive voltage transients up to 26V, without any current limiting of the source. However, if the transients have a duration of over 1 ms, the output should be clamped with a Schottky diode to ground.

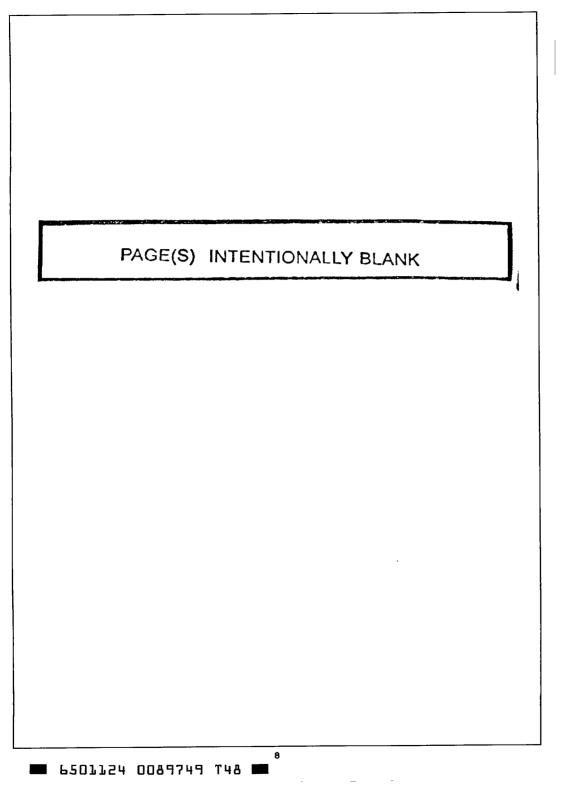


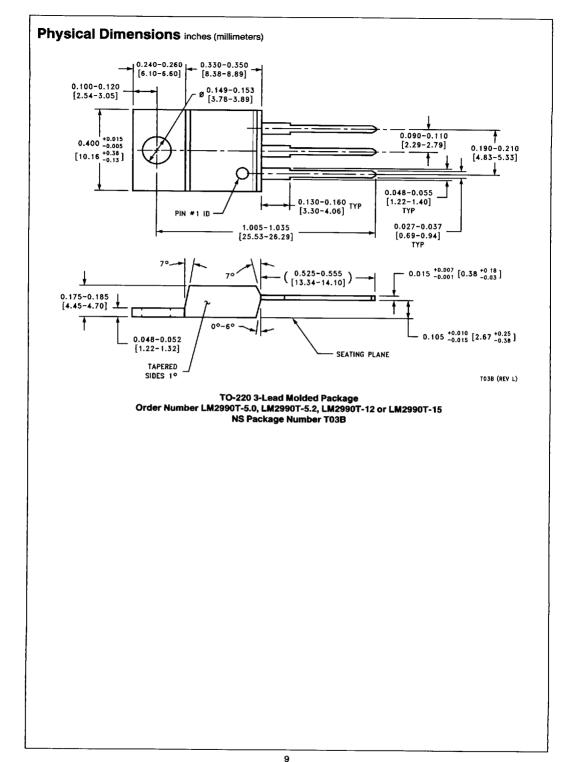
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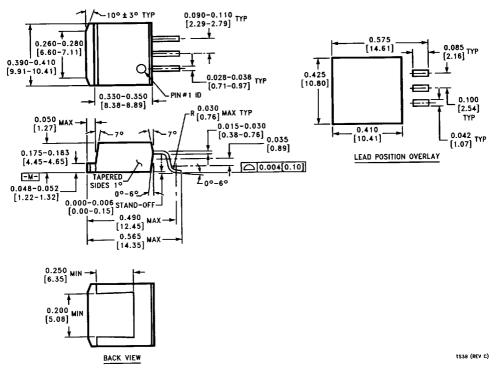






Physical Dimensions inches (millimeters)

Lit # 108040-003



TO-263 3-Lead Plastic Surface Mount Package Order Number LM2990S-5.0, LM2990S-12 or LM2990S-15 NS Package Number TS3B

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